## HAMAMATSU

PRELIMINARY DATA FEB. 2001

# PHOTOMULTIPLIER TUBES R8486, R8487

## For Vacuum Ultraviolet Light Detection Cs-Te (R8486), Cs-I (R8487) Photocathode, MgF<sub>2</sub> Window, 28 mm (1-1/8 Inch) Diameter, 9-stage, Side-on Type

#### **FEATURES**

R8487 (at 121.6 nm)......1.0  $\times$  10<sup>5</sup> A/W (Typ.)



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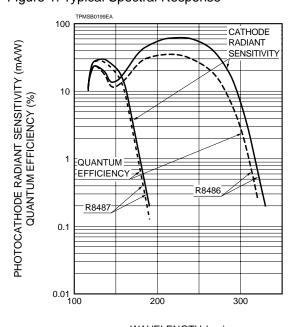
#### **APPLICATIONS**

Emission Spectroscopy, etc.

#### **GENERAL**

| Pai            | rameter              | R8486           | R8487                 | Unit  |  |  |
|----------------|----------------------|-----------------|-----------------------|-------|--|--|
| Spectral Respo | onse                 | 115 to 320      | 115 to 320 115 to 195 |       |  |  |
| Wavelength     |                      | 200             | 130                   | nm    |  |  |
| of Maximum R   | esponse              | 200             | 130                   | 11111 |  |  |
| Photocathode   | Material             | Cs-Te           | Cs-I                  | _     |  |  |
| Window Mater   | ial                  | Mg              | _                     |       |  |  |
| Minimum Effect | tive Area            | 8×              | mm                    |       |  |  |
|                | Structure            | Circula         | _                     |       |  |  |
| Dynode         | Number of Stage      | (               | _                     |       |  |  |
|                | Material             | Sb-             | _                     |       |  |  |
| Direct         | Anode to Dynode No.9 | Appr            | pF                    |       |  |  |
| Interelectrode | Anode to             | Appr            | pF                    |       |  |  |
| Capacitances   | All Other Electrodes | Аррі            | ы                     |       |  |  |
| Base           |                      | 11-pin base JED | _                     |       |  |  |
| Weight         |                      | 4               | g                     |       |  |  |
| Suitable Socke | et for Base (option) | E678            | _                     |       |  |  |

Figure 1: Typical Spectral Response



WAVELENGTH (nm)

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## PHOTOMULTIPLIER TUBES R8486, R8487

#### **MAXIMUM RATINGS (Absolute Maximum Values)**

| Parameter                        | Rating     | Unit |  |  |
|----------------------------------|------------|------|--|--|
| Supply Voltage                   |            |      |  |  |
| Between Anode and Cathode        | 1250       | V dc |  |  |
| Between Anode and Last Dynode    | 250        | V dc |  |  |
| Between Successive Dynodes       | 250        | V dc |  |  |
| Between First Dynode and Cathode | 250        | V dc |  |  |
| Average Anode Current (A)        | 0.1        | V dc |  |  |
| Ambient Temperature              | -30 to +50 | °C   |  |  |

#### CHARACTERISTICS (at 25 °C)

| Parameter                                                  | R8486                    | R8487                    | Unit |  |
|------------------------------------------------------------|--------------------------|--------------------------|------|--|
| Cathode Sensitivity                                        |                          |                          |      |  |
| Quantum Efficiency at 121 nm                               | 22.5                     | 26.0                     | %    |  |
| at 254 nm                                                  | 25.0                     | _                        | %    |  |
| Anode Sensitivity ®                                        |                          |                          |      |  |
| Radiant at 121 nm                                          | _                        | 1.0 × 10 <sup>5</sup>    | A/W  |  |
| at 254 nm                                                  | 5.2 × 10 <sup>5</sup>    | _                        | A/W  |  |
| Gain                                                       | 1.0 × 10 <sup>7</sup>    | 3.9 × 10 <sup>6</sup>    | _    |  |
| Anode Dark Current (After 30 minute storage in darkness) © | 1.0                      | 0.1                      | nA   |  |
| ENI (Equivalent Noise Input) <sup>®</sup> at 121 nm        | <del>-</del>             | 1.12 × 10 <sup>-16</sup> | W    |  |
| at 254 nm                                                  | 1.09 × 10 <sup>-16</sup> | _                        | W    |  |
| Time Response                                              |                          |                          |      |  |
| Anode Pulse Rise Time ©                                    | 2.2                      | 2.2                      | ns   |  |
| Electron Transit Time <sup>©</sup>                         | 22                       | 22                       | ns   |  |
| Transit Time Spread <sup>©</sup>                           | 1.2                      | 1.2                      | ns   |  |

#### **NOTES**

- A: Averaged over any interval of 30 seconds maximum.
- B: Measured with the same light source as Note B and with the voltage distribution ratio shown in Table 1 below.

Table 1: Voltage Distribution Ratio

| Electrode          | к | Dу | 1 D | y2 | Dy3 | Dy∠ | ı D | y5 | Dy6 | Dy7 | D; | y8 | Dy9 | F | ) |
|--------------------|---|----|-----|----|-----|-----|-----|----|-----|-----|----|----|-----|---|---|
| Distribution Ratio |   | 1  | 1   | 1  |     | 1   | 1   | 1  |     | 1   | 1  | 1  | 1   | 1 |   |

Supply Voltage=1000 V dc

K: Cathode Dy: Dynode P: Anode

- ©: Measured with the same supply voltage and voltage distribution ratio as Note E after removal of light.
- D: ENI is an indication of the photon-limited signal-to-noise ratio. It refers to the amount of light in watts to produce a signal-to-noise ratio of unity in the output of a photomultiplier tube.

$$ENI = \frac{\sqrt{2q \cdot ldb \cdot G \cdot \Delta f}}{s}$$

where  $q = Electronic charge (1.60 \times 10^{-19} coulomb)$ .

ldb = Anode dark current(after 30 minutes storage) in amperes.

G = Gain.

- $\Delta f$  = Bandwidth of the system in hertz. 1 hertz is used.
- S = Anode radiant sensitivity in amperes per watt at the wavelength of peak response.

- E: The rise time is the time for the output pulse to rise from 10 % to 90 % of the peak amplitude when the entire photocathode is illuminated by a delta function light pulse.
- E: The electron transit time is the interval between the arrival of delta function light pulse at the entrance window of the tube and the time when the anode output reaches the peak amplitude. In measurement, the whole photocathode is illuminated.
- ©: Also called transit time jitter. This is the fluctuation in electron transit time between individual pulses in the signal photoelectron mode, and may be defined as the FWHM of the frequency distribution of electron transit times.

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Figure 2: Typical Gain and Anode Radiant Sensitivity

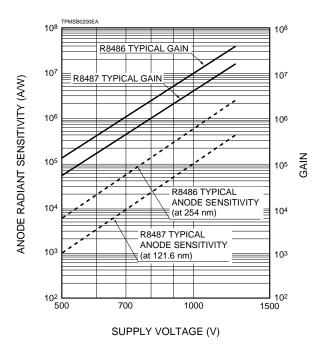


Figure 3: Typical Time Response

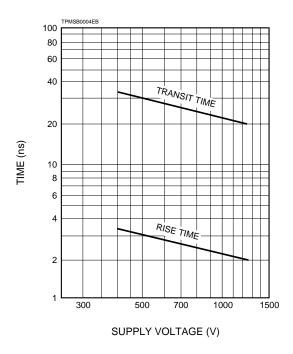


Figure 4: Dimensional Outline and Basing Diagram (Unit: mm)

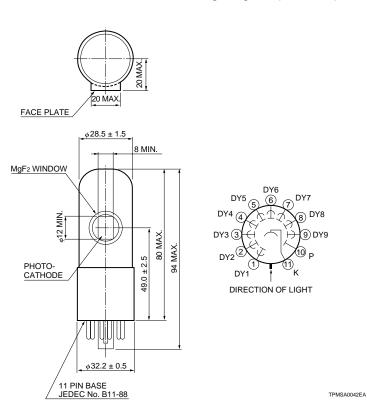
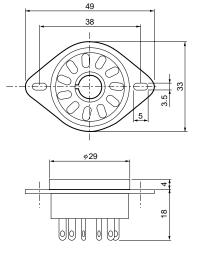


Figure 5: Socket E678-11A (Option) (Unit: mm)



TACCA0064EA

NOTE: There is a 2 mm diameter hole to exhaust inner air on the plastic base.

# PHOTOMULTIPLIER TUBES R8486, R8487

#### Warning—Personal Safety Hazards

Electrical Shock—Operating voltages applies to this device present a shock hazard.

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